

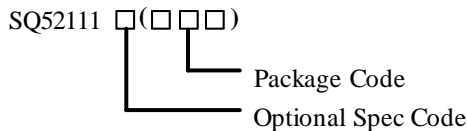
General Description

SQ52111 include both a high common mode, current sensing amplifier and a high-speed comparator configured to detect overcurrent conditions through measuring the voltage developed across a current-sensing resistor and comparing that voltage with a defined threshold limit. The device features an adjustable limit threshold range that is set using a single external resistor. This current shunt monitor can measure differential voltage signals on common-mode voltages that can vary from 0V up to 36V, independent of the supply voltage.

The open drain alert output can be configured to operate in either a transparent mode where the output status follows the input state or in a latched mode where the alert output is cleared when the latch is reset. The device alert response time is under 1.25 μ s, allowing for quick detection of overcurrent events.

SQ52111 operates from a single 2.7V to 5.5V supply, drawing a maximum supply current of 700 μ A. The device is specified over the extended operating temperature range (-40 $^{\circ}$ C to +125 $^{\circ}$ C), and is available in an 8-pin MSOP package.

Ordering Information



Ordering Number	Package type	Note
SQ52111CAP	MSOP8	

Typical Application

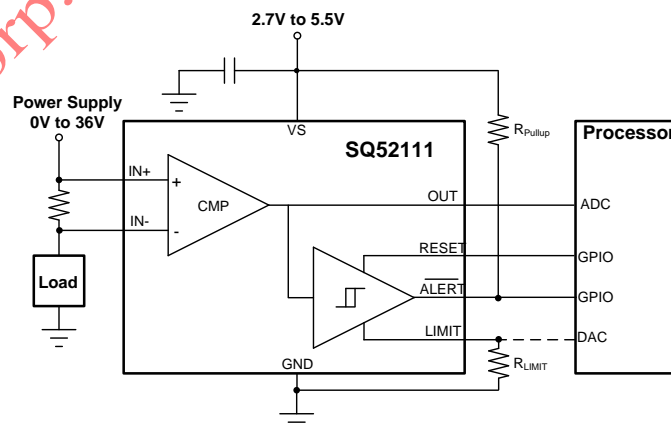


Figure 1. Typical Application

Features

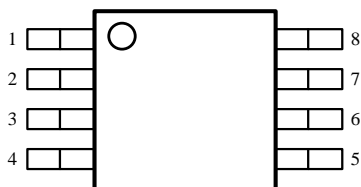
- Wide Common Mode Range: 0V to 36V
- Dual Output: Amplifier and Comparator Output
- High Accuracy Amplifier:
 - Offset Voltage: 135 μ V (Max)
 - Offset Voltage Drift: 0.5 μ V/ $^{\circ}$ C (Max)
 - Gain Error: 0.1% (Max)
 - Gain Error Drift: 10ppm/ $^{\circ}$ C (Max)
- Available Amplifier Gain: 20V/V
- Programmable Alert Threshold Setting Through a Single Resistor
- Total Alert Response Time: 1.25 μ s
- Open Drain Output with Latching Mode
- Package: MSOP8

Applications

- Overcurrent Protection
- Power-Supply Protection
- Circuit Breakers
- Computers and Servers
- Telecom Equipment
- Battery Management



Pin out (Top View)



(MSOP8)

Top mark: DYTxyz (Device code: DYT, x=year code, y=week code, z= lot number code)

Table with 3 columns: Pin Number, Pin Name, Function Description. Rows include VS, OUT, LIMIT, GND, RESET, ALERT, IN-, IN+.

Absolute Maximum Ratings

Table of Absolute Maximum Ratings including VS, Differential VIN+, Common mode, Alert output, Input voltage, Maximum Junction Temperature, and Storage Temperature Range.

Recommended Operating Conditions

Table of Recommended Operating Conditions including VS, Common mode, and Operation Temperature.

Electrical Characteristics

At $T_A=25\text{ }^\circ\text{C}$, $V_{IN}=V_{IN+}-V_{IN-}=10\text{mV}$, $V_S=5\text{V}$, $V_{IN+}=12\text{V}$ and $V_{LIMIT}=2\text{V}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Input						
Common Mode Input Voltage	V_{CM}		0		36	V
Differential Input Voltage	V_{IN}	$V_{IN}=V_{IN+}-V_{IN-}$	0		250	mV
Common Mode Rejection	CMR	$V_{IN}=0\text{V}\sim 36\text{V}$, $T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$	100	110		dB
Offset Voltage, RTI	V_{OS}			± 35	± 135	μV
Offset Voltage Drift, RTI	dV_{OS}/dT	$T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$		0.1	0.5	$\mu\text{V}/^\circ\text{C}$
Power Supply Rejection Ratio	PSR	$V_S=2.7\text{V}\sim 5.5\text{V}$, $V_{IN+}=12\text{V}$, $T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$		± 0.1	± 10	$\mu\text{V}/\text{V}$
Input Bias Current (Note 2)	I_B			120		μA
Input Offset Current (Note 3)	I_{OS}			± 0.2		μA
Output						
Gain	G			20		V/V
Gain Error		$V_{OUT}=0.5\text{V}\sim V_S-0.5\text{V}$		± 0.03	± 0.1	%
		$T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$		3	10	ppm/ $^\circ\text{C}$
Nonlinearity Error		$V_{OUT}=0.5\text{V}\sim V_S-0.5\text{V}$		± 0.01		%
Maximum Capacitive Load		No sustained oscillation		500		pF
Voltage Output						
Swing to V_S Power Supply Rail		$R_L=10\text{k}\Omega$ to GND, $T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$		$V_S-0.05$	$V_S-0.1$	V
Swing to GND		$R_L=10\text{k}\Omega$ to GND, $T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$		$V_{GND}+20$	$V_{GND}+30$	mV
Frequency Response						
Band Width	BW			550		kHz
Slew Rate	SR			4		V/ μs
Noise, RTI						
Voltage Noise Density				30		nV/ $\sqrt{\text{Hz}}$
Comparator						
Total Alert Propagation Delay	t_p	Input overdrive=1mV (Note 4) V_{IN} to Alert Propagation		1.25		μs
Slew-rate-limited t_p		V_{OUT} step=0.5V ~ 4.5V, $V_{LIMIT}=4\text{V}$		1	1.5	
Limit Threshold Output Current	I_{LIMIT}	$T_A=-40\text{ }^\circ\text{C}\sim +125\text{ }^\circ\text{C}$	79.7	80	80.3	μA
			79.2		80.8	
Comparator Offset Voltage	V_{OS}			1		mV
Hysteresis	HYS			20		mV
High Level Input Voltage	V_{IH}		2.5		6	V
Low Level Input Voltage	V_{IL}		0		0.4	V
Alert Low Level Output Voltage	V_{OL}	$I_{OL}=3\text{mA}$		70	300	mV
ALERT Terminal Leakage Input Current		$V_{OH}=3.3\text{V}$		0.1	1	μA
Digital Leakage Input Current		$0<V_{IN}<V_S$		1		μA



Power Supply						
Operating Supply Range	V _S	T _A =-40 °C~+125 °C	2.7		5.5	V
Quiescent Current	I _Q	V _{IN} =0mV, T _A =25 °C		300		μA
		V _{IN} =125mV, T _A =25 °C		500	650	
		T _A =-40 °C~+125 °C			700	

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

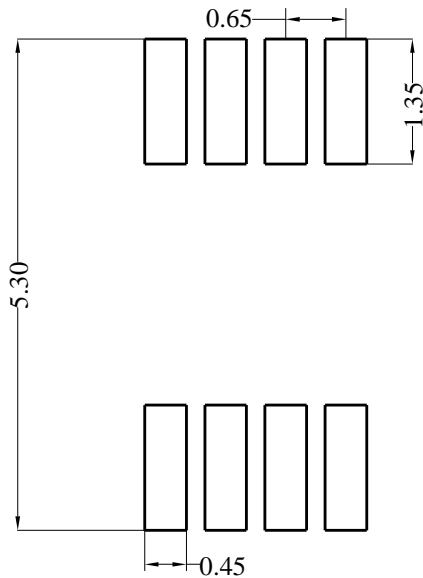
Note 2: Input bias current is decided by the sum of the input currents of the pin IN+ and IN-.

Note 3: Input offset current is decided by the error between the input currents of the pin IN+ and IN-.

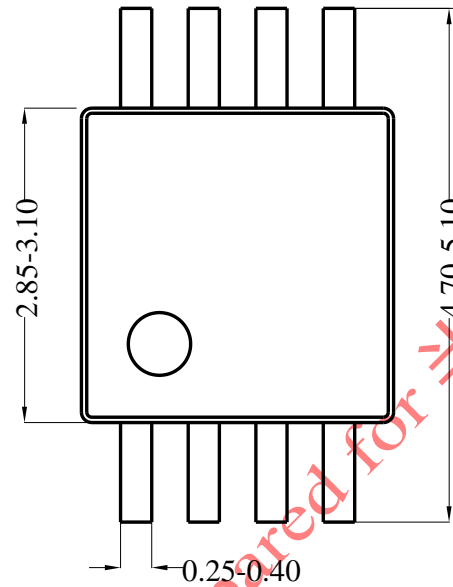
Note 4: Overdrive = (V_{OUT} - V_{LIMIT}) / Gain.

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MSOP8 Package outline & PCB layout



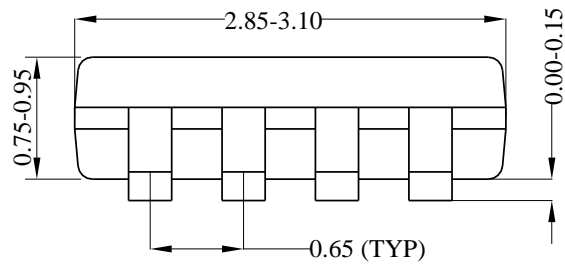
Recommended Pad Layout



Top View



Side View A



Side View B

Notes: All dimension in millimeter and exclude mold flash & metal burr.